



## **АПвЭгаПы-60 1x2000 ТУ У 31.3-00214534-060:2011**

Power cables with aluminium conductor, with XLPE, longitudinal and transverse screen sealing and strengthened polyethylene outer sheath

For the cable of this mark correspond the foreign-made analogues:

АПвПы2г (RU)

Technical cable requirements correspond to IEC 60840

Cables are used for laying:

- *in soil (trenches)*
- *in damp, partially flooded premises*
- *in ground with high humidity*
- *in non-navigable waters*
- *on difficult route sections, according to the unique specification*
- *in the air, including cable structures, if provided the additional fire protection*

It is possible to manufacture cables with extruded semiconductor layer along outer sheath.

Order entry example:

АПвЭгаПы-П-60 1x2000/95 ТУ У 31.3-00214534-060:2011

An extruded semiconductor layer along outer sheath ensures the correct testing of cable line with sections of underground laying in polymer pipes.

It is possible to manufacture cables with an integrated fiber-optic module.

Order entry example:

АПвЭгаПы-60 1x2000/95 (ОМ) ТУ У 31.3-00214534-060:2011

In conjunction with the DTS system, the integrated fiber-optic module can act as a distributed cable line temperature sensor.

It is possible to manufacture cable with sealed conductor.

Order entry example:

АПвЭгаПы-60 1x2000/95 (г) ТУ У 31.3-00214534-060:2011



## АПвЭгаПу-60 1х2000

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### TECHNICAL SPECIFICATIONS

|  |                 |                             |
|--|-----------------|-----------------------------|
| Rated voltage  | kV              | 60                          |
| Maximum voltage  | kV              | 72.5                        |
| Conductor rated area   | mm <sup>2</sup> | 2000                        |
| Minimum screen cross-section   | mm <sup>2</sup> | 35                          |
| Partial discharge factor for rated voltage, not more than                        | pC              | 6                           |
| Permissible short circuit current across the screen of minimum cross-section     | kA              | 10.2                        |
| Maximum permissible short-circuit current in core                                | kA              | 188                         |
| Permissible continuous current rating by aerial laying *                         |                 |                             |
| • in trefoil formation with double-side screen earthing                          | A               | 1444                        |
| • in trefoil formation with single-side screen earthing or cross screen earthing | A               | 1761                        |
| • plane with double-side screen earthing   | A               | 1233                        |
| • plane with single-side screen earthing or cross screen earthing                | A               | 2106                        |
| Permissible continuous current rating by burial *                                |                 |                             |
| • in trefoil formation with double-side screen earthing                          | A               | 1008                        |
| • in trefoil formation with single-side screen earthing or cross screen earthing | A               | 1269                        |
| • plane with double-side screen earthing   | A               | 819                         |
| • plane with single-side screen earthing or cross screen earthing                | A               | 1355                        |
| Maximum permissible conductor temperature  |                 |                             |
| • Continuous   | °C              | +90                         |
| • in emergency operation   | °C              | +130                        |
| • at short circuit   | °C              | +250                        |
| Operating temperature range  | °C              | -60 ... +50                 |
| Minimum bending radius by laying   | mm              | 1616                        |
| Rated outer diameter of the cable (for reference) **                             | mm              | 101                         |
| Cable weight (approximate)   | kg/km           | 12980                       |
| Rated factory cable length and gross weight of the delivery on the drums ***     | m, t            | # 30УД-130: **** 550 • 10.0 |

#### Notes:

When ordering it is necessary to agree the factory length of the product with the manufacturer

\* Long permissible current loads are calculated for the following conditions: conductor temperature 90 °C, air temperature 30 °C, soil temperature 20 °C, load factor 1.0, thermal resistivity of soil 1.0 °K·m/W, laying depth in the ground 1.5 m, while laying in flat formation the distance between cables in clear is equal to the cable diameter, while laying in trefoil formation cables are laid side by side

\*\* The external diameter may differ from the rated up to ± 10 %

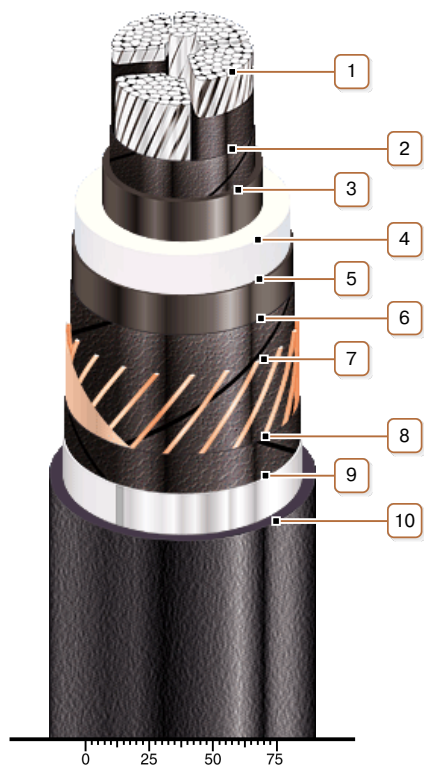
\*\*\* Отклонение фактической массы брутто от указанного значения может составлять ± 7 %

\*\*\*\* Option delivery on not full drum



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### CONSTRUCTION

#### 1. Aluminium multiwire compacted conductor

Notes:

- It is possible to manufacture cable with sealed conductor.
- Conductor segment twisting is not illustrated

#### 2. Lapping layer of semiconductive swellable tape

#### 3. Inner extruded semiconducting layer

#### 4. XLPE insulation

#### 5. Outer extruded semiconducting layer

#### 6. Lapping layer of semiconductive swellable tape

#### 7. Copper screen

Note: It is possible to manufacture a cable with a fiber optic module built into the screen, including as a DTS system sensor

#### 8. Lapping layer of semiconductive swellable tape

#### 9. Alumopolymer tape

#### 10. Strengthened polyethylene outer sheath

Note: It is possible to manufacture cable with extruded semiconductor layer along outer sheath